



N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY				
Part Number	$V_{(BR)DSS}$ Min (V)	$r_{DS(on)}$ Max (Ω)	$V_{GS(th)}$ (V)	I_D (A)
2N7000	60	5 @ $V_{GS} = 10$ V	0.8 to 3	0.2
2N7002		7.5 @ $V_{GS} = 10$ V	1 to 2.5	0.115
VQ1000J		5.5 @ $V_{GS} = 10$ V	0.8 to 2.5	0.225
VQ1000P		5.5 @ $V_{GS} = 10$ V	0.8 to 2.5	0.225
BS170		5 @ $V_{GS} = 10$ V	0.8 to 3	0.5

FEATURES

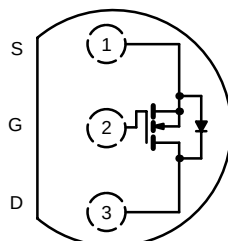
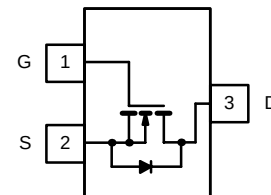
- Low On-Resistance: 2.5 Ω
- Low Threshold: 2.1 V
- Low Input Capacitance: 22 pF
- Fast Switching Speed: 7 ns
- Low Input and Output Leakage

BENEFITS

- Low Offset Voltage
- Low-Voltage Operation
- Easily Driven Without Buffer
- High-Speed Circuits
- Low Error Voltage

APPLICATIONS

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

TO-226AA
(TO-92)Top View
2N7000TO-236
(SOT-23)

Top View

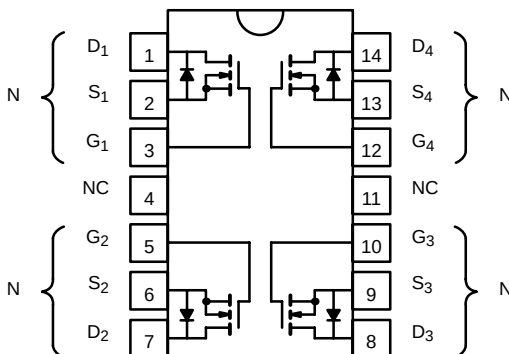
Marking Code: 72w//

72 = Part Number Code for 2N7002

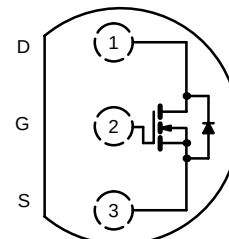
w = Week Code

// = Lot Traceability

Dual-In-Line



Top View

Plastic: VQ1000J
Sidebrazed: VQ1000PTO-92-18RM
(TO-18 Lead Form)

Top View

BS170

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)								
Parameter	Symbol	2N7000	2N7002	Single		Total Quad	BS170	Unit
				VQ1000J	VQ1000P	VQ1000J/P		
Drain-Source Voltage	V_{DS}	60	60	60	60		60	V
Gate-Source Voltage—Non-Repetitive	V_{GSM}	± 40	± 40	± 30			± 25	
Gate-Source Voltage—Continuous	V_{GS}	± 20	± 20	± 20	± 20		± 20	
Continuous Drain Current ($T_J = 150^\circ\text{C}$)	$T_A = 25^\circ\text{C}$	I_D	0.2	0.115	0.225	0.225	0.5	A
	$T_A = 100^\circ\text{C}$		0.13	0.073	0.14	0.14	0.175	
Pulsed Drain Current ^a	I_{DM}	0.5	0.8	1	1			
Power Dissipation	$T_A = 25^\circ\text{C}$	P_D	0.4	0.2	1.3	1.3	2	W
	$T_A = 100^\circ\text{C}$		0.16	0.08	0.52	0.52	0.8	
Thermal Resistance, Junction-to-Ambient	R_{thJA}	312.5	625	96	96	62.5	156	$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150						$^\circ\text{C}$

Notes

a. Pulse width limited by maximum junction temperature.

b. $t_p \leq 50 \mu\text{s}$.SPECIFICATIONS—2N7000 AND 2N7002 ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Test Conditions	Typ ^a	Limits				Unit
				2N7000		2N7002		
				Min	Max	Min	Max	
Static								
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 10 μA	70	60		60		V
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 1 mA	2.1	0.8	3			
		V _{DS} = V _{GS} , I _D = 0.25 mA	2.0			1	2.5	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 15 V			± 10			nA
		V _{DS} = 0 V, V _{GS} = ± 20 V				± 100		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 48 V, V _{GS} = 0 V			1			μA
		T _C = 125°C			1000			
		V _{DS} = 60 V, V _{GS} = 0 V					1	
		T _C = 125°C					500	
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 10 V, V _{GS} = 4.5 V	0.35	0.075				A
		V _{DS} = 7.5 V, V _{GS} = 10 V	1			0.5		
Drain-Source On-Resistance ^b	r _{DS(on)}	V _{GS} = 4.5 V, I _D = 0.075 A	4.5		5.3			Ω
		V _{GS} = 5 V, I _D = 0.05 A	3.2				7.5	
		T _C = 125°C	5.8				13.5	
		V _{GS} = 10 V, I _D = 0.5 A	2.4		5		7.5	
		T _J = 125°C	4.4		9		13.5	
Forward Transconductance ^b	g _{fs}	V _{DS} = 10 V, I _D = 0.2 A		100		80		mS
Common Source Output Conductance ^b	g _{os}	V _{DS} = 5 V, I _D = 0.05 A	0.5					
Dynamic								
Input Capacitance	C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V f = 1 MHz	22		60		50	pF
Output Capacitance	C _{oss}		11		25		25	
Reverse Transfer Capacitance	C _{rss}		2		5		5	

**SPECIFICATIONS—2N7000 AND 2N7002 ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)**

Parameter	Symbol	Test Conditions	Typ ^a	Limits				Unit
				2N7000		2N7002		
				Min	Max	Min	Max	
Switching ^d								
Turn-On Time	t _{ON}	V _{DD} = 15 V, R _L = 25 Ω I _D ≅ 0.5 A, V _{GEN} = 10 V, R _G = 25 Ω	7		10		ns	
Turn-Off Time	t _{OFF}		7		10			
Turn-On Time	t _{ON}	V _{DD} = 30 V, R _L = 150 Ω I _D ≅ 0.2 A, V _{GEN} = 10 V, R _G = 25 Ω	7			20		
Turn-Off Time	t _{OFF}		11			20		

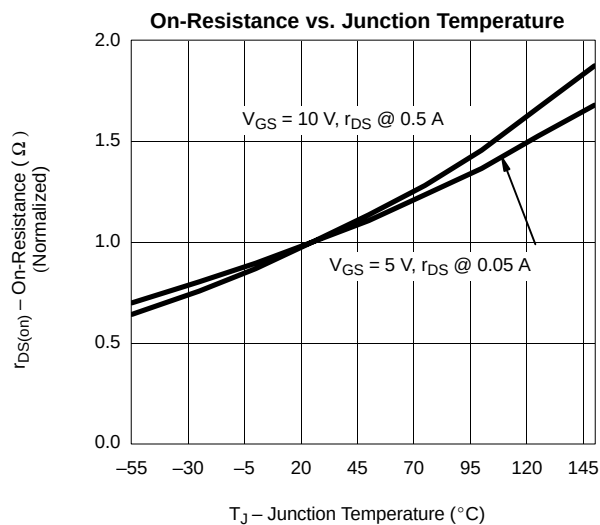
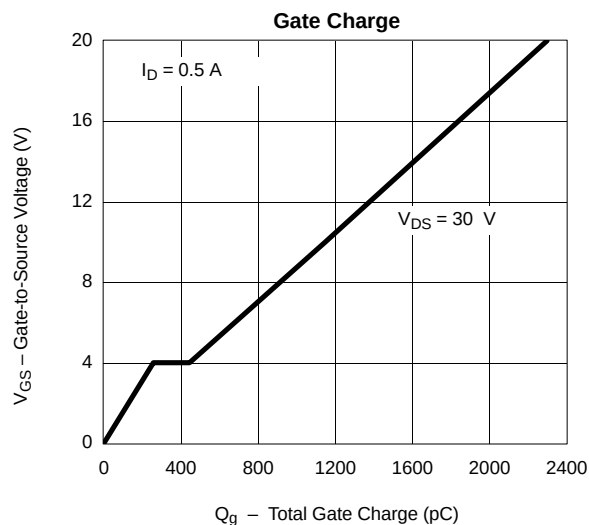
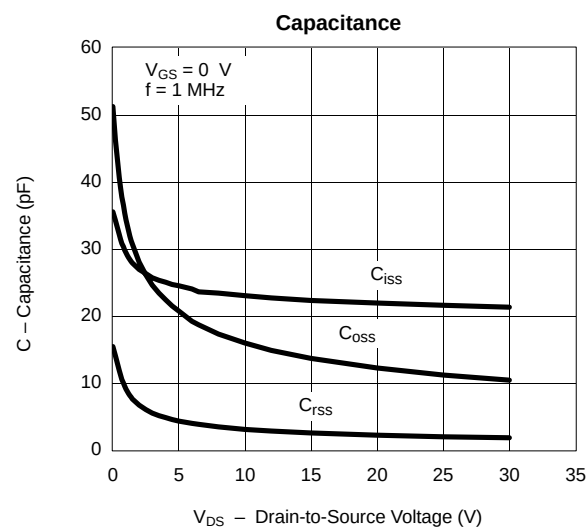
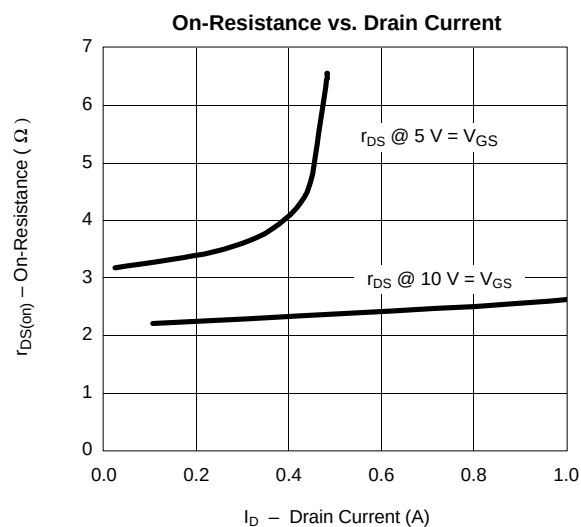
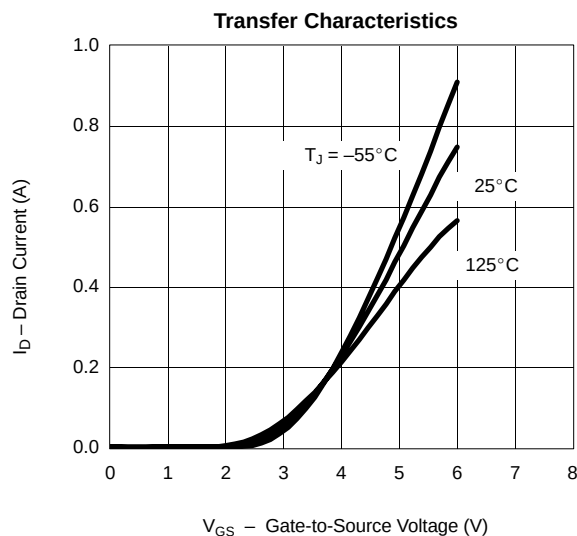
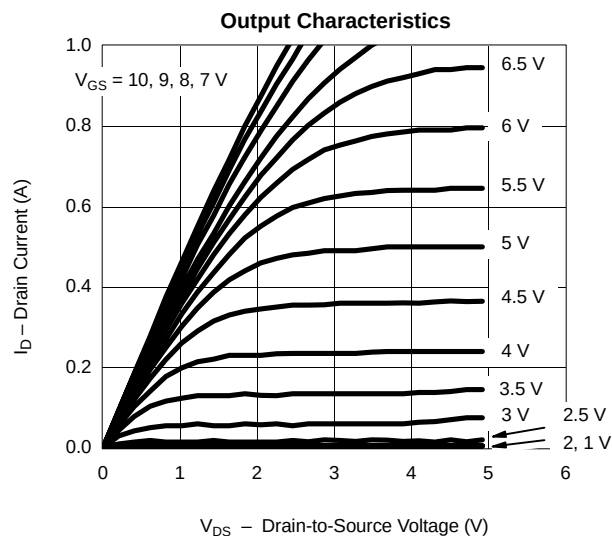
SPECIFICATIONS—VQ1000J/P AND BS170 ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

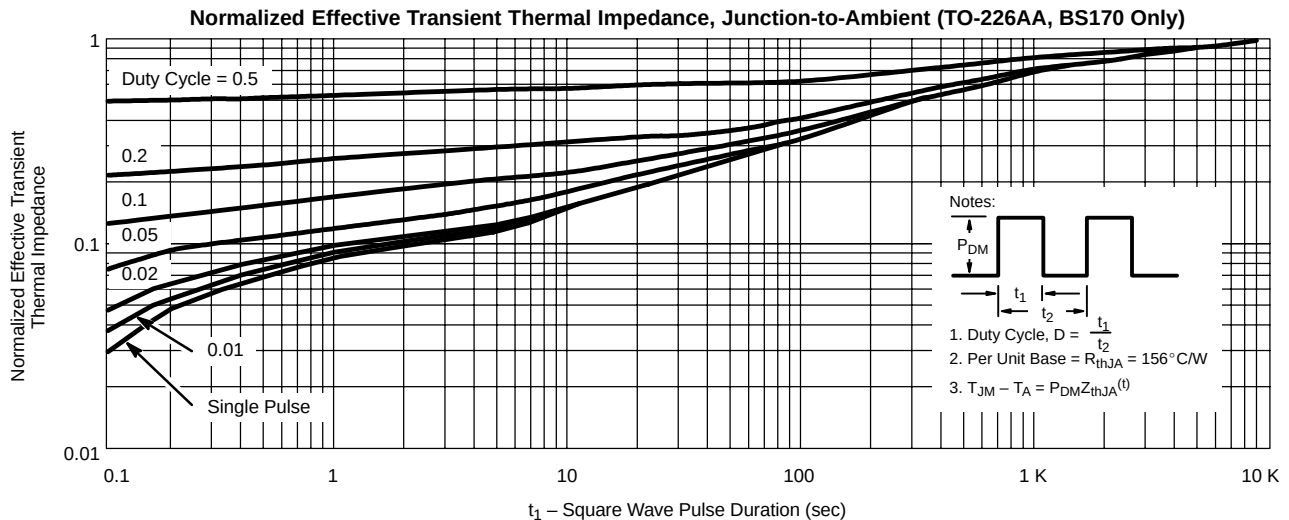
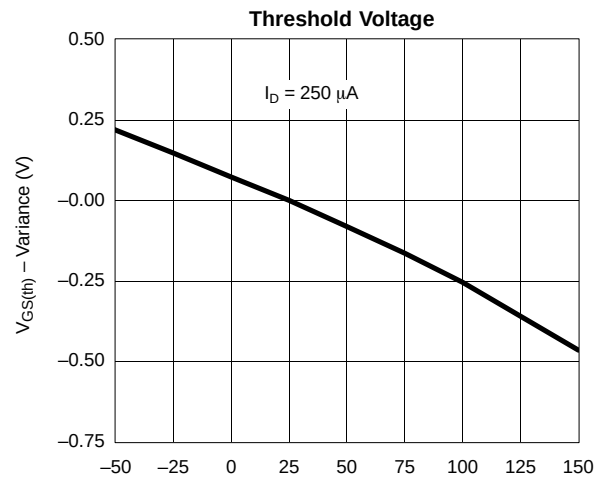
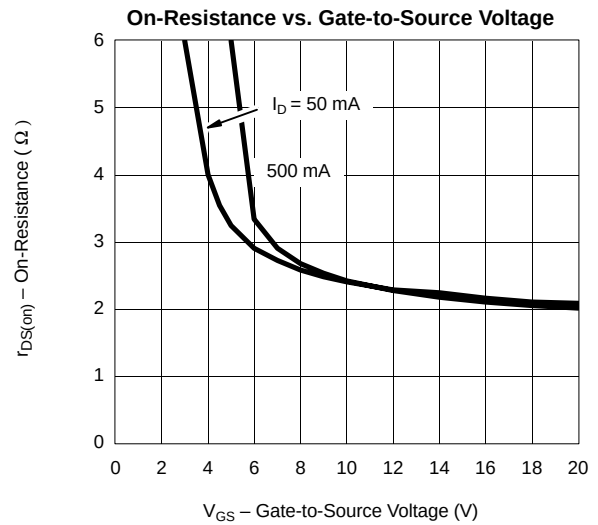
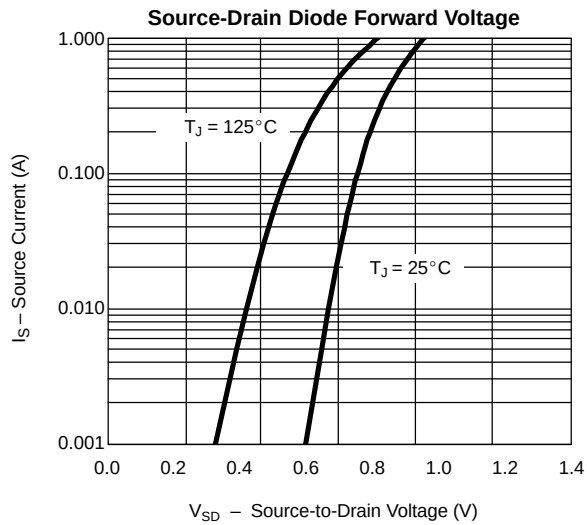
Parameter	Symbol	Test Conditions	Typ ^a	Limits				Unit
				VQ1000J/P		BS170		
				Min	Max	Min	Max	
Static								
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 100 μA	70	60		60		V
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 1 mA	2.1	0.8	2.5	0.8	3	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 10 V			± 100			nA
		T _J = 125°C			± 500			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 0 V, V _{GS} = ± 15 V					± 10	μA
		V _{DS} = 25 V, V _{GS} = 0 V					0.5	
		V _{DS} = 48 V, V _{GS} = 0 V, T _J = 125°C			500			
		V _{DS} = 60 V, V _{GS} = 0 V			10			
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 10 V, V _{GS} = 10 V	1	0.5				A
Drain-Source On-Resistance ^b	r _{DS(on)}	V _{GS} = 5 V, I _D = 0.2 A	4		7.5			Ω
		V _{GS} = 10 V, I _D = 0.2 A	2.3				5	
		V _{GS} = 10 V, I _D = 0.3 A	2.3		5.5			
		T _J = 125°C	4.2		7.6			
Forward Transconductance ^b	g _{fs}	V _{DS} = 10 V, I _D = 0.2 A				100		mS
		V _{DS} = 10 V, I _D = 0.5 A		100				
Common Source Output Conductance ^b	g _{os}	V _{DS} =5 V, I _D = 0.05 A	0.5					
Dynamic								
Input Capacitance	C _{iss}	V _{DS} =25 V, V _{GS} = 0 V f = 1 MHz	22		60		60	pF
Output Capacitance	C _{oss}		11		25			
Reverse Transfer Capacitance	C _{rss}		2		5			
Switching ^d								
Turn-On Time	t _{ON}	V _{DD} = 15 V, R _L = 23 Ω I _D ≅ 0.6 A, V _{GEN} = 10 V, R _G = 25 Ω	7		10			ns
Turn-Off Time	t _{OFF}		7		10			
Turn-On Time	t _{ON}	V _{DD} = 25 V, R _L = 125 Ω I _D ≅ 0.2 A, V _{GEN} = 10 V, R _G = 25 Ω	7				10	
Turn-Off Time	t _{OFF}		7				10	

Notes

- a. For DESIGN AID ONLY, not subject to production testing.
b. Pulse test: $PW \leq 80\ \mu\text{s}$ duty cycle $\leq 1\%$.
c. This parameter not registered with JEDEC.
d. Switching time is essentially independent of operating temperature.

VNBF06

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

**TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)**



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